

Electronic Supplementary Information for

Ordered Arrays of Defect-Modified Ferroelectric Polymer for Non-volatile Memory with Minimized Energy Consumption

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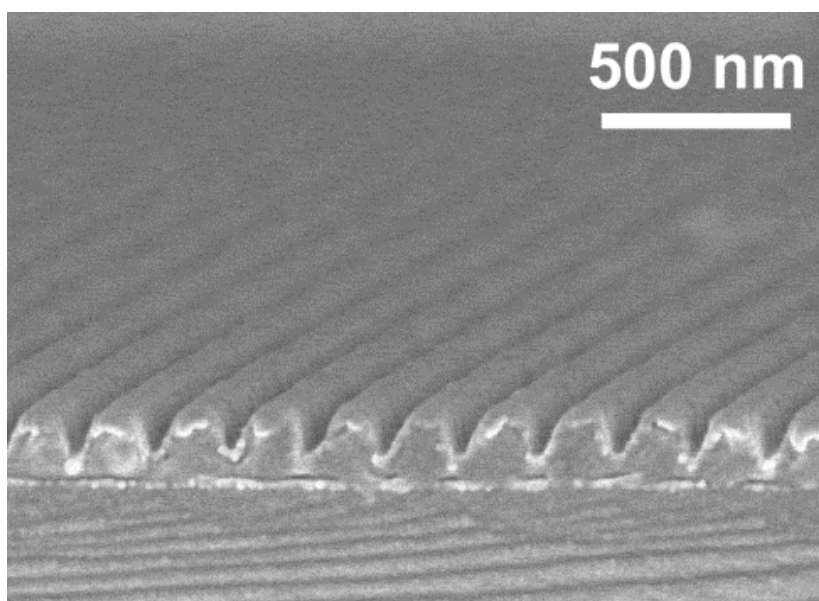


Figure S1 Cross-section SEM image of nanoimprinted terpolymer Film.